



Article

# Analysis of Scalable Resonant DC–DC Converter Using GaN Switches for xEV Charging Stations

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**Abstract:** In this research, an innovative electric vehicle (EV) charger is designed and presented for xEV charging stations. The key feature of our system is a scalable, interleaved inductor–inductor–capacitor (iL<sup>2</sup>C) DC–DC converter operation. The proposed system employs two parallel L<sup>2</sup>C converters with 8–GaN switches on the primary side and a shared rectifier circuit on the secondary side. This configuration not only amplifies the resonant tank internal currents and losses generated by the switches but also improves current sharing. A novel closed-loop technique is proposed with a constant-voltage method of operation, along with a hybrid control scheme of variable frequency + phase shift modulation (VFPSM). To examine the controller and converter's performance, an experimental demonstration is conducted under varying load conditions, including full load, half load, and light load, where the source voltage and load voltage are maintained at constant levels of 400 V<sub>in</sub> and 48 V<sub>0</sub>, respectively. Furthermore, line regulation is conducted and verified to accommodate a broad input voltage range of 300 V<sub>in</sub>–500 V<sub>in</sub> and 500 V<sub>in</sub>–300 V<sub>in</sub> while maintaining an output voltage of 48 V<sub>0</sub> at 3.3 kW, 1.65 kW, and 0.33 kW with a peak efficiency of 98.2%.

**Keywords:** electric vehicle charger; DC–DC converter; scalable; iL<sup>2</sup>C resonant converter; hybrid control strategy; gallium nitride



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## 1. Introduction

Due to the contamination caused by toxic gases, carbon emissions, and unpredictable weather patterns, conventional internal combustion engines are approaching their maximum capabilities. There is a global initiative to implement environmentally friendly transportation in order to mitigate the effects of climate change. Electric vehicles (EVs) are increasingly becoming popular due to their environmentally advantageous nature, aiming to replace internal combustion engines (ICEs) and reduce carbon dioxide emissions [1–3]. By transitioning to electric vehicles, such as battery electric vehicles (BEVs), fuel cell electric vehicles (FCEVs), hybrid electric vehicles (HEVs), ultra-capacitor electric vehicles (UCEVs), solar-charged electric vehicles (SCEVs), and plug-in hybrid electric vehicles (PHEVs), we can significantly reduce pollutants [4,5]. The goal of achieving a carbon-free society by 2030 in Europe and 2050 in India is ambitious but achievable with the swift adoption of EVs and the development of robust charging infrastructure. This transition not only contributes to environmental preservation but also promotes technological advancement and energy independence. The increasing demand for electric vehicles necessitates the development of a strong and efficient charging infrastructure. The information in [6,7] covers power electronics for several applications such as solar energy, fuel cells, renewable energy, and electric cars. It also discusses optimization approaches for various charging topologies. Figure 1 illustrates a standard block diagram of a charging infrastructure.



**Figure 1.** Typical block diagram of charging power conversion system.

In the present scenario, the EV industry is looking for a scalable design that can operate over wide operating ranges and easily adjust to different power requirements [8]. The need for scalability is increased because battery charging technology has improved over a wide range from 48 V to 800 V and even larger in some cases. The scalable designs are helpful with their quick adaptability of operation to the desired voltage range [9]. Resonant converters are more popular for their merit of operation over wide operating ranges; hence, this paper deals with an advanced resonant converter named the  $iL^2C$  converter, which is an extension of the  $L^2C$  converter [10,11].

According to our understanding,  $L^2C$  resonant converters are gaining popularity in comparison to numerous traditional DC-DC converters [12,13]. This is due to their inherent benefits, including primary-side zero voltage switching (ZVS) operation across all load circumstances and secondary-side zero current switching (ZCS) operation with synchronous rectification [14,15]. The ZVS function can be compromised if the switching frequency, denoted as  $f_s$ , is too low. Consequently, designers must take this into account when dealing with applications that require a wide voltage gain [16,17]. Furthermore, the use of the  $L^2C$  converter as an EV charger is subject to many limitations. For instance, augmenting the load capacity at a high power density results in amplified voltage and current fluctuations, which can potentially harm the product [18,19]. The volume of the resonant tank is limited, resulting in increased circulating current and reduced efficiency [20].

This work introduces an  $iL^2C$  converter as an electric vehicle charger to address the research gap in  $L^2C$  converters [21]. In order to increase the load capacity, this converter employs two  $L^2C$  converters operating in parallel. Consequently, the power losses in the transformer are reduced during high-current applications. Over time, numerous control techniques have been suggested to enhance soft switching, ensure precise regulation, and minimize the circulating current [22,23]. All of these control methods can be employed in different working areas of the converter, such as when the switching frequency ( $f_s$ ) is less than the resonant frequency ( $f_r$ ), when  $f_s$  is equal to  $f_r$ , and when  $f_s$  is more than  $f_r$ . These methods have an impact on the regulation of the converter. This article presents a hybrid control technique called the variable frequency + phase shift modulation (VFPSM) scheme. The strategy operates at a specified current value in either the zero current switching (ZCS) or zero voltage switching (ZVS) operating area. Furthermore, the  $iL^2C$  DC-DC converter utilizes wideband gap semiconductor-based E-mode (enhancement mode) GaN technology.

The research contributions of this paper are as follows:

- The modeling of a scalable  $iL^2C$  resonant converter with operation is presented.
- A hybrid control strategy is suggested and derived to improve the regulations.
- Simulations are presented for various load and line regulating conditions to check the converter performances.
- The experimental setup is demonstrated using E-mode GaN technology at 3.3 kW as an EV charger with an efficiency of 98.2%.

## 2. Modeling and Operation of $iL^2C$ Converter Topology

Figure 2 illustrates the resonant DC-DC topology of the  $iL^2C$ , while Figure 3 depicts identical waveforms. It consists of two resonant circuits, each with a switching topology that incorporates a primary and secondary rectifier circuit utilizing a single diode bridge. It

functions by employing a phase angle of 180° between the gate signals of two switching circuits. Equation (1) denotes that the resonant frequency of the converter is 150 kHz [21]. Additionally, the functioning of two switching topologies is comparable throughout their entire operational cycle; thus, the equations are examined in relation to the resonant network 1 and converter 1 [21,22]. The graphical representation of the gain performances of the converter is shown in Figure 4.

$$f_r = \frac{1}{2\pi\sqrt{L_r * C_r}} \tag{1}$$

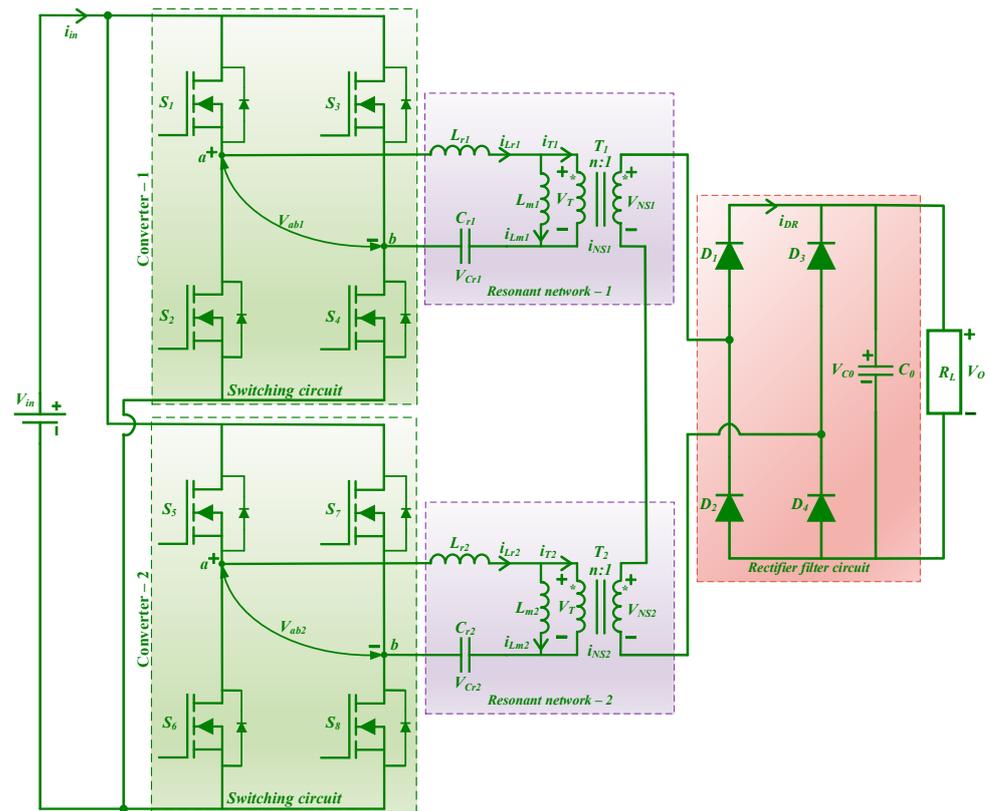


Figure 2.  $iL^2C$  DC-DC power converter topology [21].

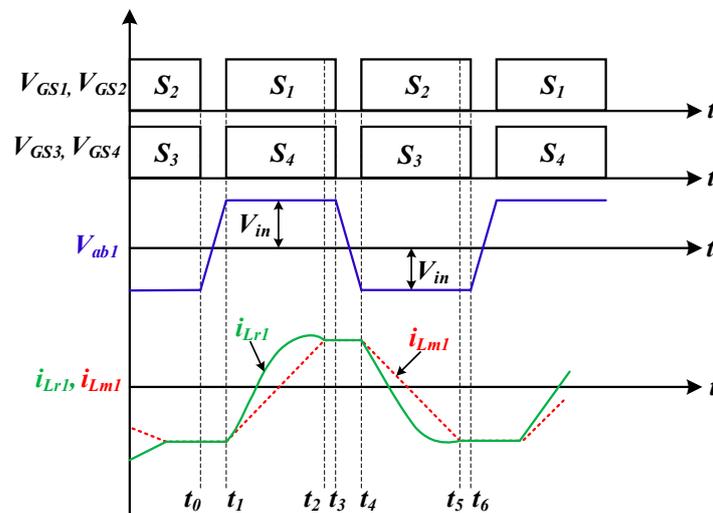


Figure 3. Identical waveforms of interleaved  $L^2C$  DC-DC switching network 1 [21].

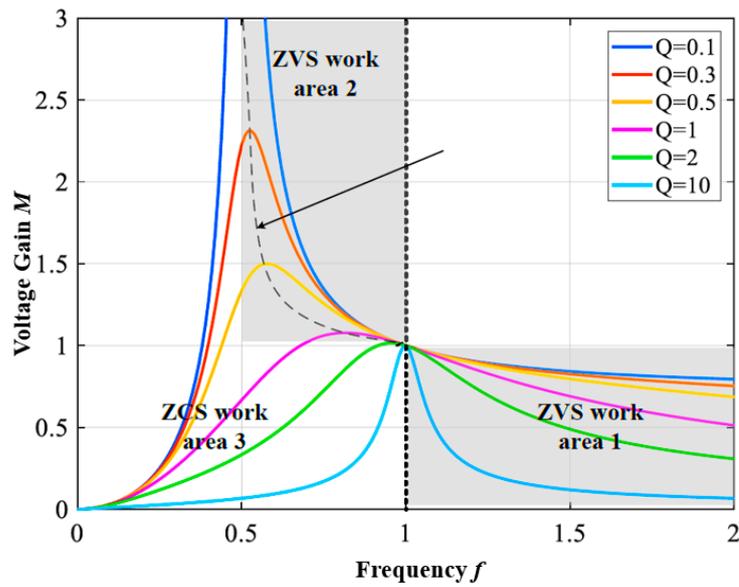


Figure 4. Voltage gain  $M$  vs. frequency  $f$  by varying the  $Q$ -factor [21].

Stage 1: All secondary-side diodes are deactivated prior to time zero, while switches  $S_2$  and  $S_3$  are in the active state. During the time interval  $t_0$ – $t_1$ , the switches  $S_2$  and  $S_3$  are deactivated, while the body diodes  $S_1$  and  $S_4$  are activated using a negative resonant current of  $i_{Lr1}$ .

Stage 2: The voltage throughout transformer 1  $T_1$  is equivalent to the input voltage  $V_{in}$  between time points  $t_1$  and  $t_2$ , and the switches  $S_1$ ,  $S_4$  and diodes  $D_1$ ,  $D_4$  are all in the ON state. Concurrently, the additional current of  $i_{NS1}$  conducts via the filter capacitor  $C_0$ , while the resonant inductor  $L_{r1}$  begins to circulate through the resonant capacitor  $C_{r1}$ . The voltage of the magnetizing inductance  $L_{m1}$  is specified by Equation (2), and the current increases incrementally. Furthermore, the voltage across  $V_{NS1}$  from time  $t_1$  to time  $t_2$  is equivalent to the output voltage  $V_0$ , as calculated in Equation (3), and subsequently, the voltage at the resonant tank is described in Equation (4) [24].

$$L_{m1} = \frac{V_0}{n} \tag{2}$$

$$V_{NS1} = V_0 \tag{3}$$

$$\begin{cases} i_{Lr1}(t) = I_0 \cos(\omega_r t) + \frac{(nV_{in} - V_0 - nV_0)}{nZ_r} \sin(\omega_r t) \\ V_{Cr1}(t) = I_0 Z_r \sin(\omega_r t) + \left( V_0 + \frac{V_0}{n} - V_{in} \right) \cos(\omega_r t) \\ \quad + V_{in} - \frac{V_0 - V_{C0}}{n} \end{cases} \tag{4}$$

Stage 3: The switches  $S_2$  and  $S_3$  are activated at intervals  $t_2$  through  $t_3$ , resulting in a positive current flow at  $i_{Lr1}$ , while the secondary-side diode rectifier circuit remains in an OFF state.

Stage 4: During the time intervals  $t_3$  to  $t_4$ , the secondary-side diodes  $D_2$  and  $D_4$  are in the ON position in relation to the switches  $S_2$  and  $S_3$ , because of the negative current circulation in  $i_{NS1}$ . Consequently, the secondary-side voltage of the transformer is  $-V_{C0}$ , which is exceedingly low, and the current  $i_{Lm1}$  progressively diminishes. Conduction between the resonant inductor  $L_{r1}$  and the resonant capacitor  $C_{r1}$  commences simultaneously with the secondary current of  $i_{NS1}$  charging the filter capacitor  $C_0$ . Equation (5) represents the voltage  $V_{NS1}$  at this juncture, while Equation (6) depicts the state space equation [24–26].

$$V_{NS1} = -V_0 \tag{5}$$

$$\begin{cases} i_{Lr1}(t) = I_{Lr1}(t_2)\cos(\omega_r t) + \frac{(nV_{in}-V_0-nV_{Cr1}(t_2))\sin(\omega_r t)}{nZ_r} \\ V_{Cr1}(t) = I_{Lr1}(t_2)Z_r\sin(\omega_r t) + \left(V_{Cr1}(t_2) - \frac{V_0}{n} - V_{in}\right)\cos(\omega_r t) \\ \quad + V_{in} + \frac{V_0}{n} \end{cases} \quad (6)$$

Stage 5: From time  $t_4$  to time  $t_5$ , the components  $D_2$  and  $D_3$  are both in the ON state, while the secondary-side transformer current  $i_{NS1}$  is reduced to zero. Equation (7) represents the secondary side of the transformer voltage; consequently, the magnetizing inductance drops gradually [27,28]. Additionally, resonance occurs between the resonant capacitor  $C_{r1}$  and the resonant inductor  $L_{r1}$ .

$$V_{NS1} = -V_0 \quad (7)$$

The state space equations for stage 5 are defined in Equation (8) below:

$$\begin{cases} i_{Lr1}(t) = I_{Lr1}(t_4)\cos(\omega_r t) + \frac{(nV_{in}+V_0-nV_{Cr1}(t_4))\sin(\omega_r t)}{nZ_r} \\ V_{Cr1}(t) = I_{Lr1}(t_4)Z_r\sin(\omega_r t) + \left(V_{Cr1}(t_4) - \frac{V_0}{n} - V_{in}\right)\cos(\omega_r t) \\ \quad + V_{in} + \frac{V_0}{n} \end{cases} \quad (8)$$

Stage 6: From time  $t_5$  to time  $t_6$ , the current  $i_{NS1}$  on the secondary side of the transformer is entirely negative, accompanied by the absence of any diodes. The magnetizing inductance  $i_{Lm1}$  begins to resonate with the resonant capacitor  $C_{r1}$  and inductor  $L_{r1}$  at this time.

The critical parameters of the  $iL^2C$  converter for every single component are mentioned in [21–24]; the nominal input voltage is 400 V, and the output voltage is 48 V at a power range of 3.3 kW and a filter capacitor value of 100  $\mu$ F, respectively. The associated step-by-step engineering calculations then followed with the appropriate values.

Equations (9)–(11) were utilized to derive a transformer  $T_1$  turn ratio of 8.82, as well as the maximum and minimum values of voltage gain of the  $iL^2C$  converter under the specified operating conditions.

$$n = \frac{V_{in\_min}}{V_0\_min} \quad (9)$$

$$M_{min} = \frac{n * V_0\_min}{V_{in\_max}} \quad (10)$$

$$M_{max} = \frac{n * V_0\_max}{V_{in\_min}} \quad (11)$$

where  $n$  is transformer turn ratio,  $V_{in\_max}$  and  $V_{in\_min}$  are maximum and minimum input voltages,  $V_0\_max$  and  $V_0\_min$  are maximum and minimum output voltages, followed by maximum and minimum voltage gain  $M_{max}$  and  $M_{min}$  [24].

The resonant tank design of the resonant inductance  $L_{r1}$  was 22.11  $\mu$ H; the capacitance  $C_{r1}$  was 50.94 nF; the impedance  $Z_{01}$  and the magnetizing inductance  $L_{m1}$  were 20.83  $\Omega$  and 23  $\mu$ H respectively with an equivalent resistance  $R_{ac1}$  of 22.12  $\Omega$  and 55.81  $\Omega$  as the minimum and maximum values. The formulas are mentioned in Equations (12)–(16) [29,30].

$$R_{ac1} = \frac{8n^2}{\pi^2} * R_L \quad (12)$$

$$L_{m1} = \frac{n^2}{f_r} * \frac{V_{o\_crit}}{4 * n * I_{sc} + [\pi^2 * L * M_{crit} - 4] * I_{o\_crit}} \quad (13)$$

$$L_{r1} = L * L_{m1} \quad (14)$$

$$C_{r1} = \frac{1}{L_{r1} * (2\pi f_r)^2} \quad (15)$$

$$Z_{01} = \sqrt{\frac{L_{r1}}{C_{r1}}} \tag{16}$$

### 3. Control Strategy

There are now multiple control approaches being studied for resonant converters mainly based on fixed-or variable-frequency techniques and phase shifting strategies. Nevertheless, in practical use, each of them possesses distinct constraints when it comes to converters operating within a wider range of input and output voltages. Typically, frequency modulation is effective but necessitates intricate magnetic construction, whereas the phase shifting approach is straightforward to build but challenging for a wide variety of input voltages [24]. This paper presents a hybrid control methodology, known as the VFPSM method, for an iL<sup>2</sup>C converter. The VFPSM method ensures consistent control strategy performance throughout all areas.

The switching frequency  $f_s$  is determined by comparing the output voltage  $V_0$  to the reference input voltage  $V_{ref}$ , relying on the provided error voltage. The voltage control oscillator (VCO) can be utilized to compare the input and output voltage values [22–24], while also driving the gate signals. Figure 5 displays the control circuit. The controller regulates the output voltage  $V_0$  and modulates the current, referred to as the CV mode of operation. The third-order transfer function, specified in Equation (17) with sub-equations in Equations (18)–(22), is valuable for constructing the outer feedback compensator [31–33].

$$Gvf(s) = \frac{V(s)_0}{w(s)_s} = G_{dc} \frac{X_{eq}^2 + R_{eq}^2}{(s^2 L_e^2 + s L_e R_{eq} + X_{eq}^2) (1 + s R_L C_f) + R_{eq} (s L_e + R_{eq})} \tag{17}$$

$$L_e = L_r + \frac{1}{C_r \Omega_s^2} = L_r \left( 1 + \frac{\Omega_0^2}{\Omega_s^2} \right) \tag{18}$$

$$R_{eq} = \frac{8}{\pi^2} n^2 R_L \tag{19}$$

$$X_{eq} = \Omega_s L_r - \frac{1}{\Omega_s C_r} \tag{20}$$

$$L_n = \frac{L_m}{L_r} \tag{21}$$

$$Q = \frac{\sqrt{\frac{L_r}{C_r}}}{n^2 R_L} \tag{22}$$

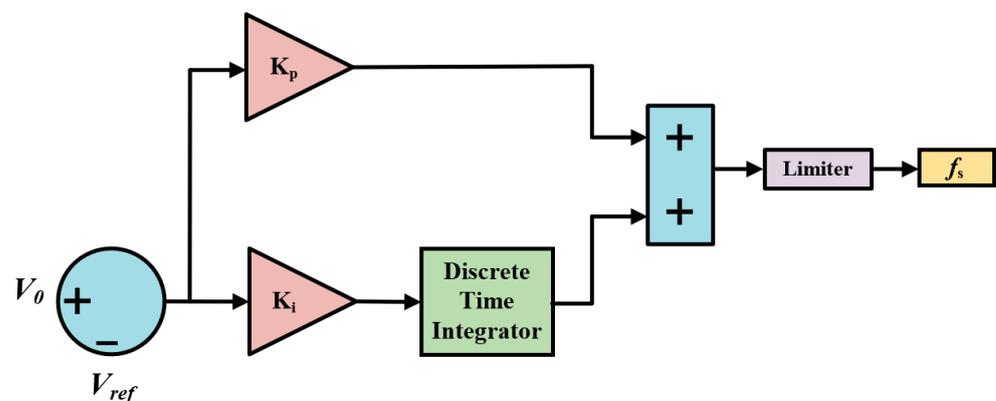


Figure 5. Closed-loop controller using VCO for CV mode of operation [24].

The development of the switching frequency design was concluded based on the information provided in Figure 5. This design enables the generation of pulses that may be used to switch the switches ON and OFF [34,35]. The 180-degree phase shift technique is employed to control the input voltage within the wide range of  $300 V_{in}$ – $500 V_{in}$ , while the VFPSM methodology ensures precise regulation at both the line and load sides [36]. The operation of converters 1 and 2 involves a switching process that utilizes the phase shifting approach known as “before  $180^\circ$ ” and “after  $180^\circ$ ”, respectively, as seen in Figure 6 [37,38].

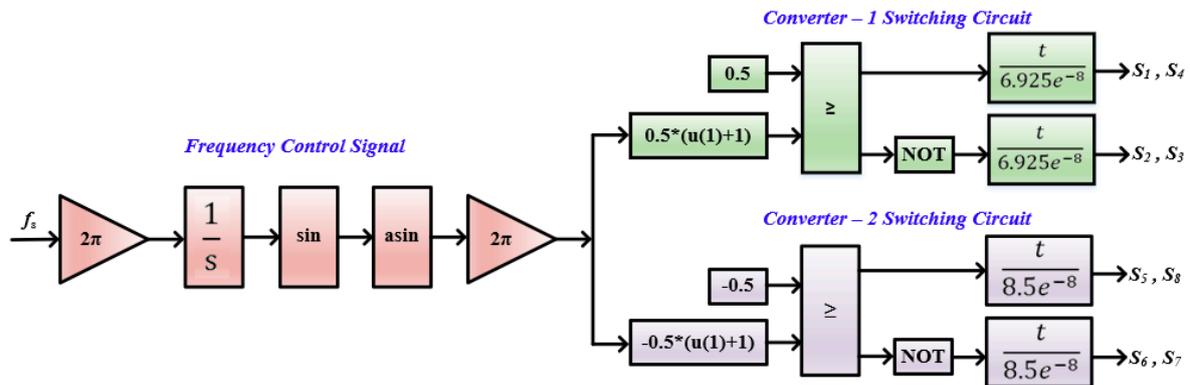


Figure 6. VFPSM control strategy control block diagram [24].

#### 4. Simulation and Experimental Validation

MATLAB/Simulink was utilized to conduct the simulation analysis of the  $iL^2C$  converter employing the VFPSM control technique. The essential design variables are enumerated in [24]. The evaluation of the converter is provided for various case studies. In the first instance, the nominal input and output voltage under full load, half load, and light load conditions were examined. The nominal input voltage of  $400 V_{in}$  is depicted as a constant in Figure 7.

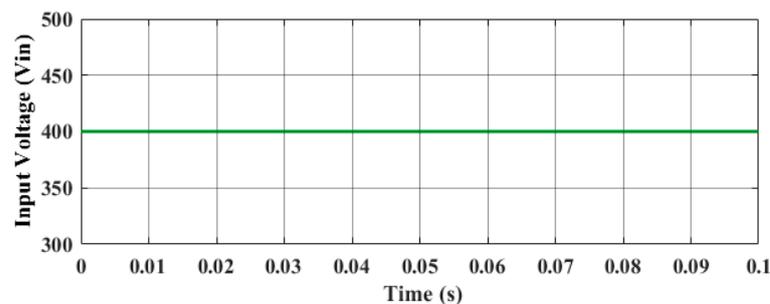


Figure 7. Rated input voltage waveform ( $V_{in} = 400 V$ ).

The outcomes of the simulated converter were assessed under controlled nominal load conditions of  $68.75 A$  and  $48 V_0$  at maximum load ( $3.3 kW$ ). Figure 8 shows the resonant tank waveforms of converter 1 and converter 2, and the converter load voltage and current waveforms are presented in Figure 9. The voltage and current ripple measurements indicated a deviation of  $+0.5 V$  ( $+1.04\%$ ) at a rated output of  $48 V_0$  and approximately  $+0.65 A$  ( $+0.94\%$ ) at a full load current of  $68.75 A$ , respectively.

Figure 10 shows the resonant tank waveforms of converter 1 and converter 2; Figure 11 presents the simulated results for the half load condition, which is at  $1.65 kW$ ,  $48 V$ , and  $34.375 A$ , respectively. At an output of  $48 V_0$ , both ripple voltages and currents were determined to have a voltage variance of  $+0.3 V$  ( $+0.62\%$ ) and a current variance of approximately  $+0.175 A$  ( $+0.5\%$ ) at a half load current of  $38.375 A$ .

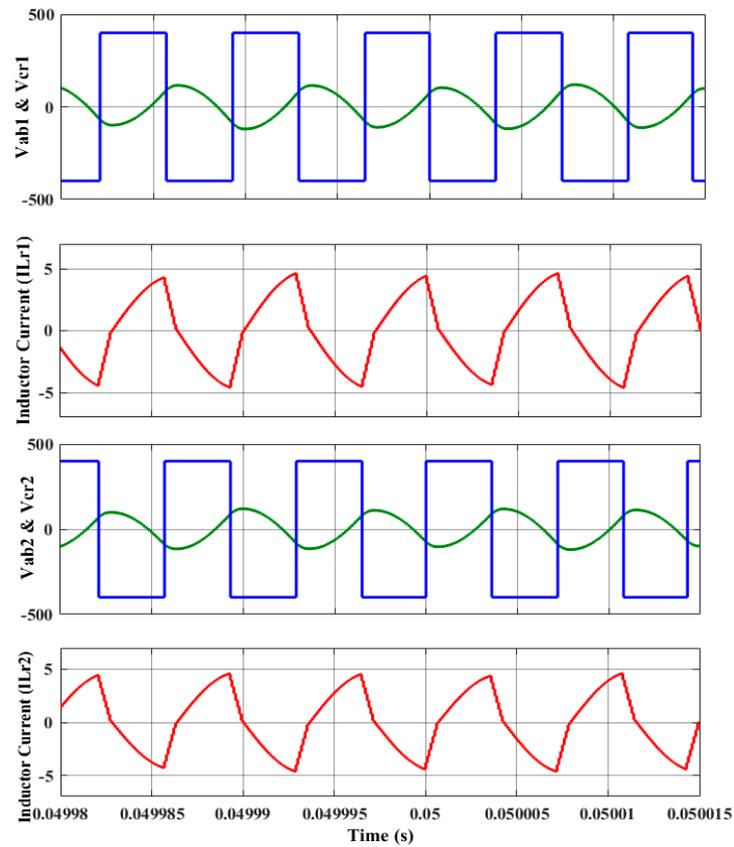


Figure 8. Resonant tank waveforms of converter 1 and converter 2 at 3.3 kW.

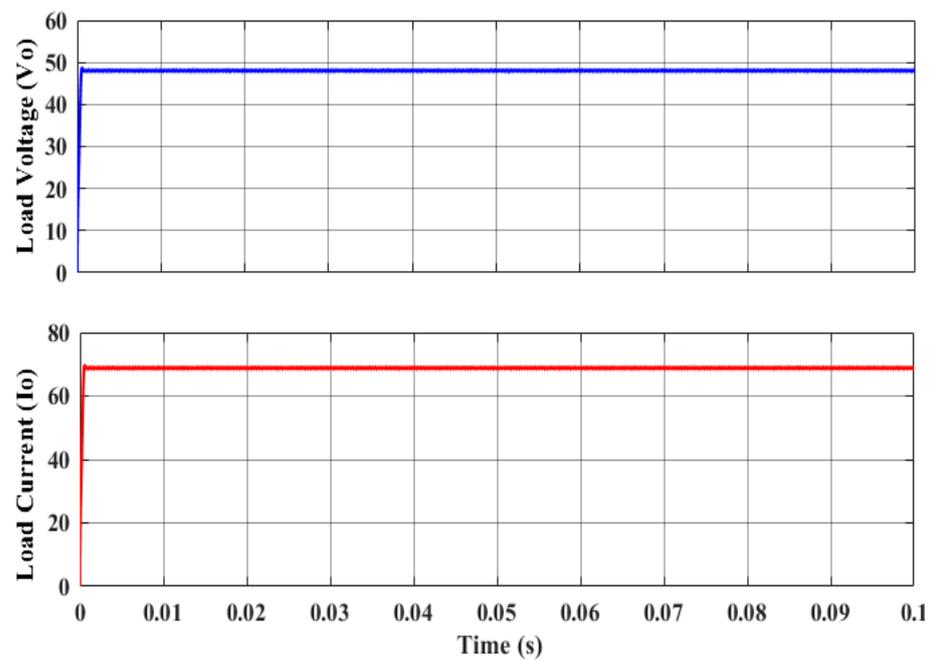


Figure 9. Load voltage and current waveforms at full load (3.3 kW).

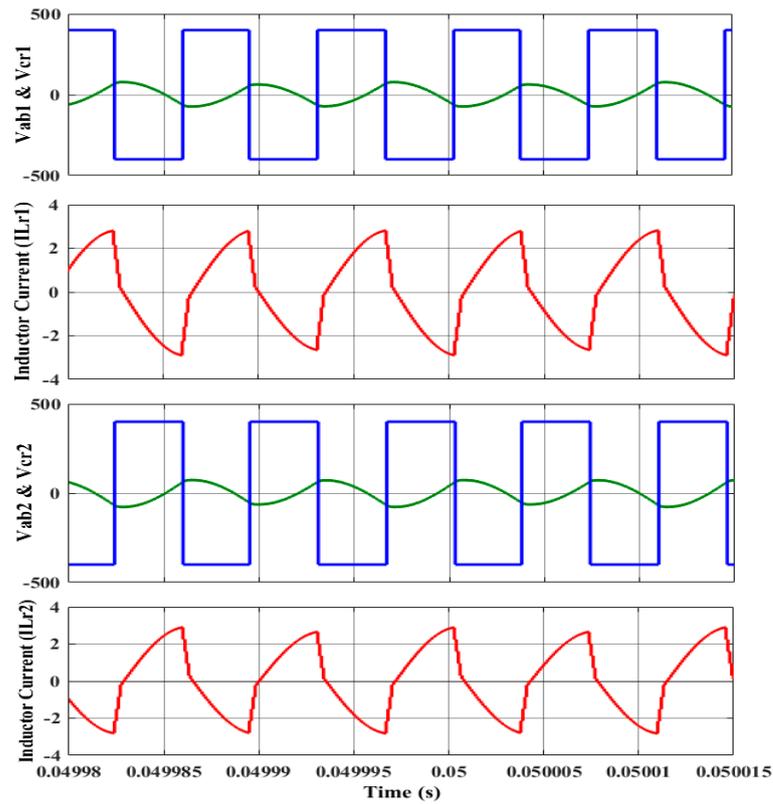


Figure 10. Resonant tank waveforms of converter 1 and converter 2 at 1.65 kW.

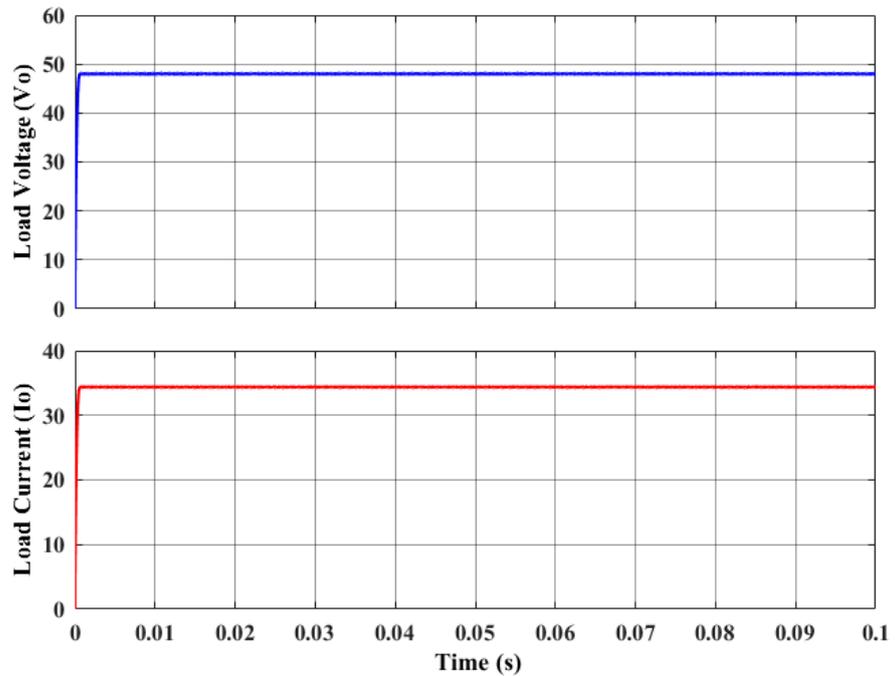


Figure 11. Load voltage and current waveforms at half load (1.65 kW).

Figure 12 shows the resonant tank waveforms of converter 1 and converter 2; Figure 13 presents the simulated results at a light load which is 10% of the rated load, i.e., 0.33 kW, 48 V, and 6.875 A, respectively. At an output of  $48 V_0$ , both ripple voltages and currents were determined to have a voltage variance of +0.15 V (+0.31%) and a current variance of approximately +0.017 A (+0.25%) at a half load current of 6.875 A.

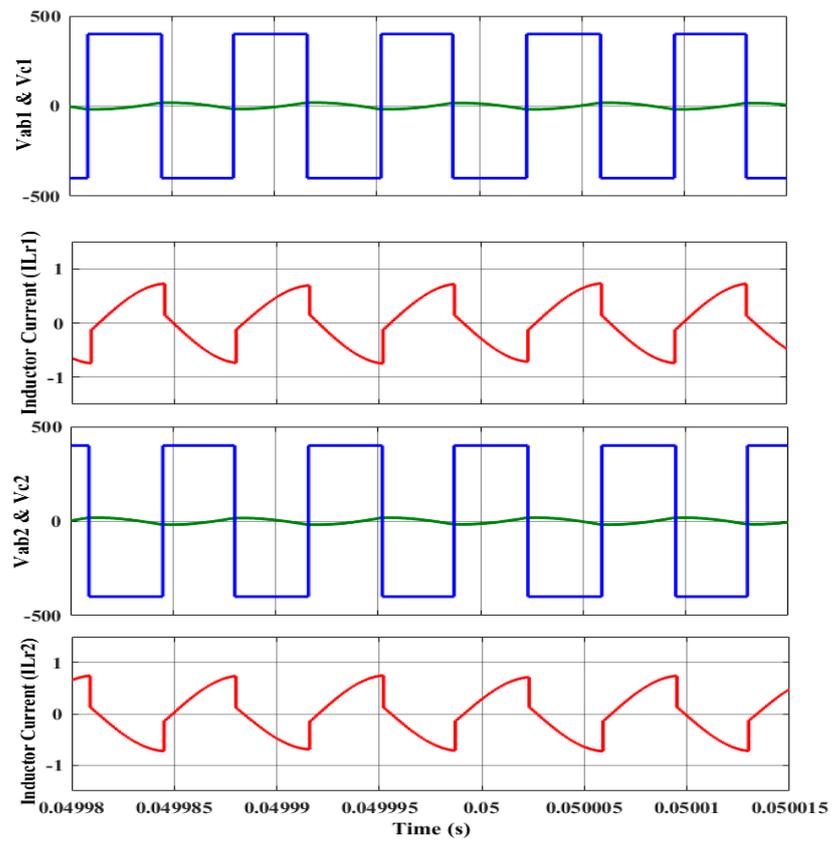


Figure 12. Resonant tank waveforms of converter 1 and converter 2 at 0.33 kW.

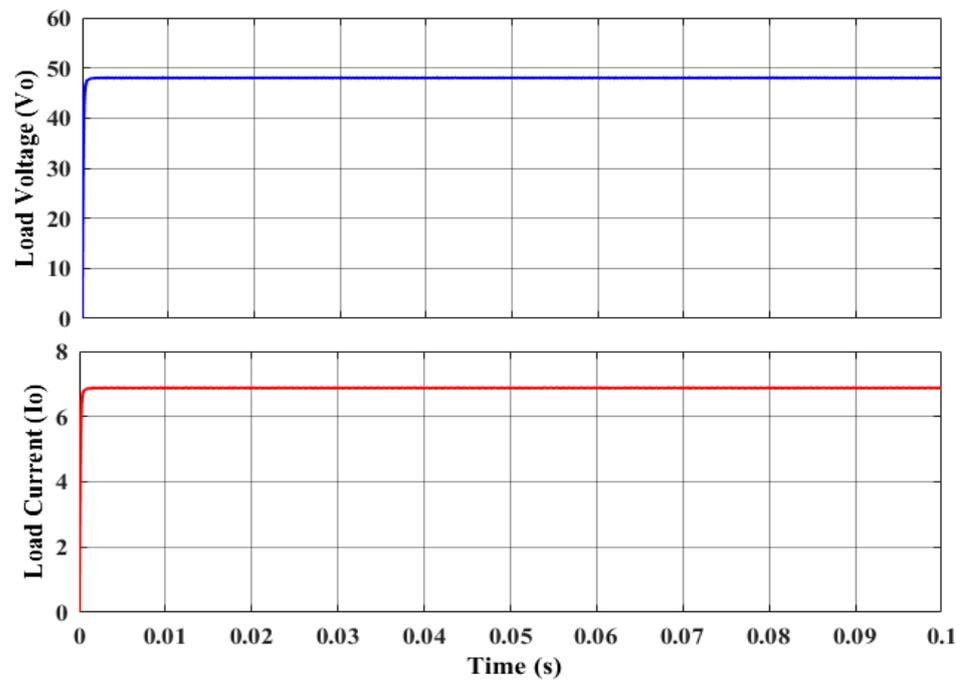
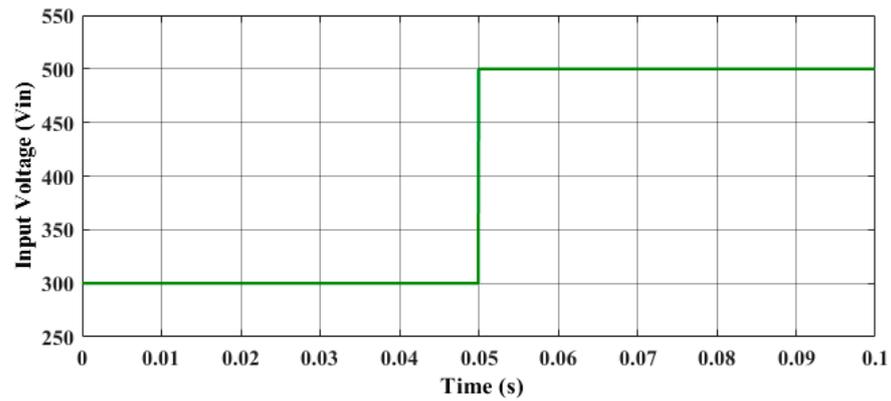


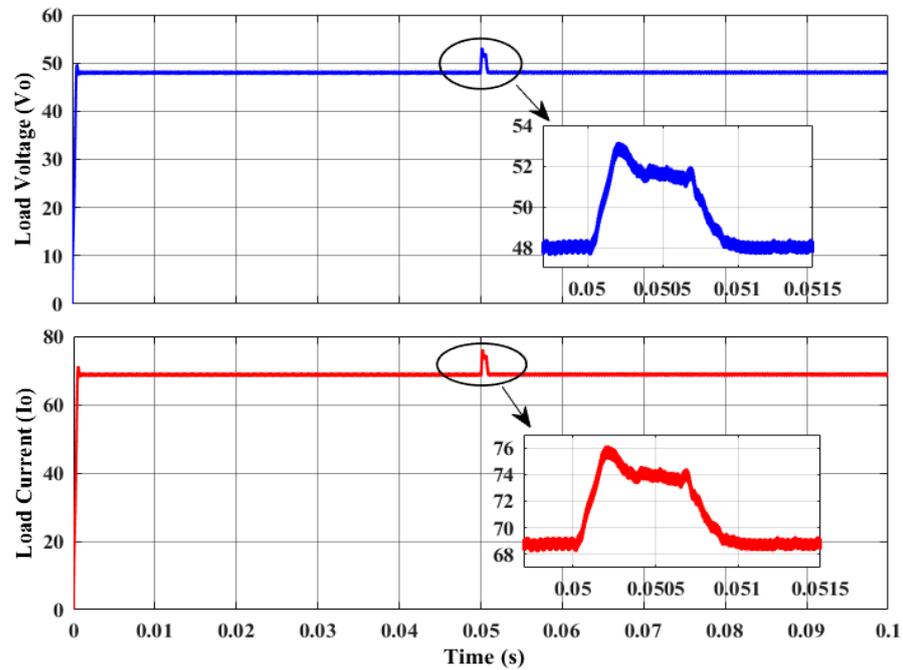
Figure 13. Load voltage and current waveforms at light load (0.33 kW).

#### 4.1. Dynamic Performance Analysis of $iL^2C$ Converter for $300 V_{in}$ – $500 V_{in}$ under Various Load Conditions

In this section, the dynamic performance of the  $iL^2C$  converter with a variable input voltage of  $300$ – $500 V_{in}$  and an output voltage that stays constant at  $48 V_0$  is evaluated. The voltage increased abruptly from  $300$  to  $500 V_{in}$  at  $0.05$  s, as depicted in Figure 14. Figure 15 illustrates the load voltage of  $48$  V and current waveforms at  $3.3$  kW. The sudden variation in load voltage and current took place at  $0.05$  s; the enlarged figures are also provided, and the settling time was within  $1.1$  ms.



**Figure 14.** Sudden change in input voltage from  $300 V_{in}$  to  $500 V_{in}$  at  $0.05$  s.



**Figure 15.** Step change in load voltage and current waveforms from  $300 V_{in}$  to  $500 V_{in}$  at  $3.3$  kW.

Figure 16 illustrates the load voltage of  $48$  V and current waveforms at  $1.65$  kW. The sudden variation in load voltage and current took place at  $0.05$  s; the enlarged figures are also provided, and the settling time was within  $1.0$  ms.

Figure 17 illustrates the load voltage of 48 V and current waveforms at 0.33 kW. The sudden variation in load voltage and current took place at 0.05 s; the enlarged figures are also provided, and the settling time was within 1.3 ms.

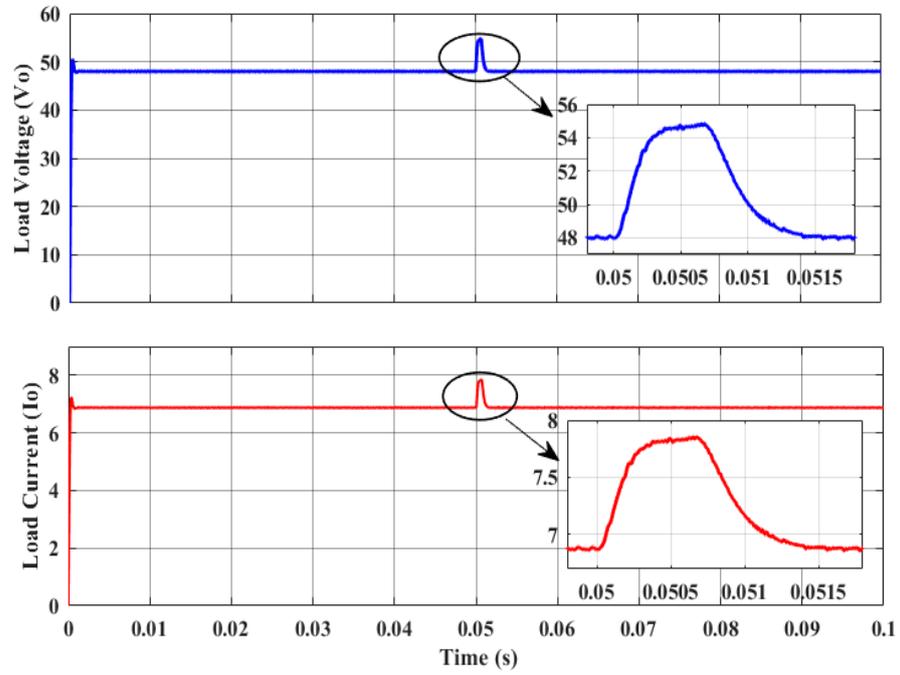


Figure 16. Step change in load voltage and current waveforms from 300  $V_{in}$  to 500  $V_{in}$  at 1.65 kW.

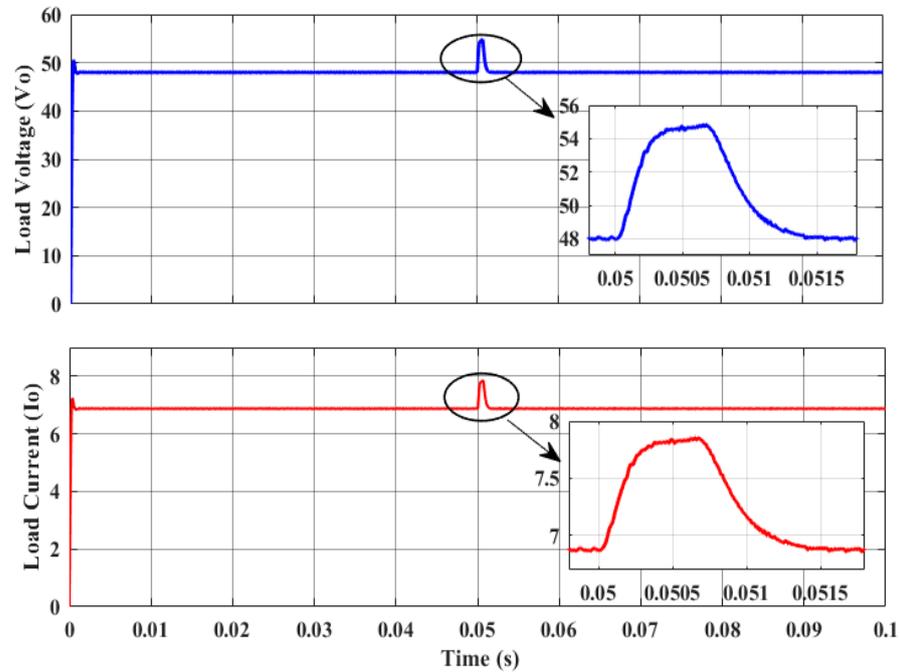


Figure 17. Step change in load voltage and current waveforms from 300  $V_{in}$  to 500  $V_{in}$  at 0.33 kW.

#### 4.2. Dynamic Performance Analysis of $iL^2C$ Converter for $500 V_{in}$ – $300 V_{in}$ under Various Load Conditions

In this section, the dynamic performance of the  $iL^2C$  converter with a variable input voltage of  $500$ – $300 V_{in}$  and an output voltage that stays constant at  $48 V_0$  is evaluated. The voltage increased abruptly from  $500$  to  $300 V_{in}$  at  $0.05$  s, as depicted in Figure 18. Figure 19 illustrates the load voltage of  $48$  V and current waveforms at  $3.3$  kW. The sudden variation in load voltage and current took place at  $0.05$  s; the enlarged figures are also provided, and the settling time was within  $1.2$  ms.

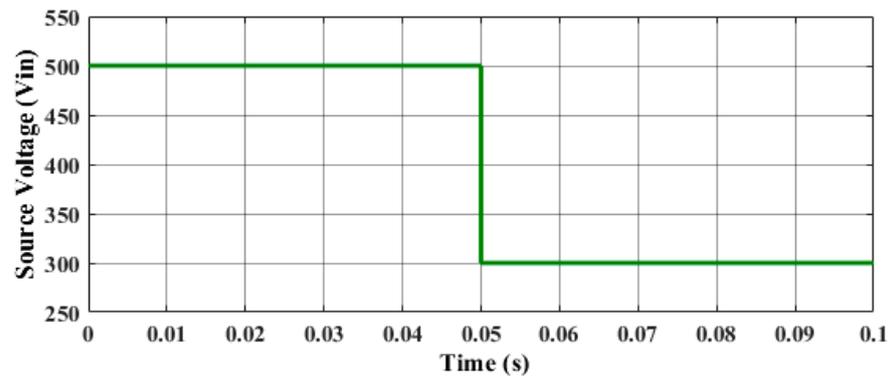


Figure 18. Sudden change in input voltage from  $500 V_{in}$  to  $300 V_{in}$  at  $0.05$  s.

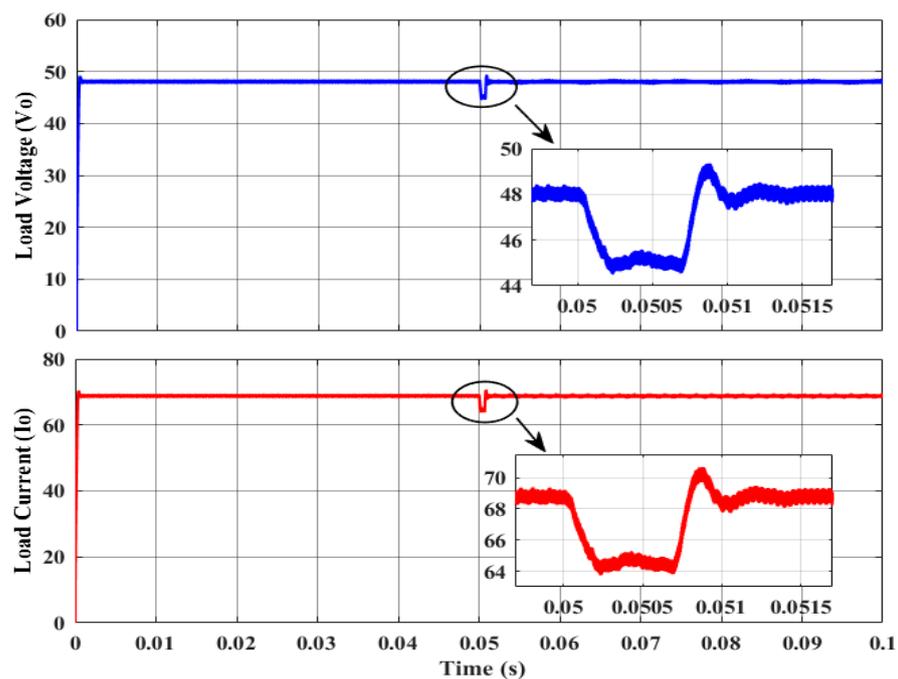


Figure 19. Step change in load voltage and current waveforms from  $500 V_{in}$  to  $300 V_{in}$  at  $3.3$  kW.

Figure 20 illustrates the load voltage of  $48$  V and current waveforms at  $1.65$  kW. The sudden variation in load voltage and current took place at  $0.05$  s; the enlarged figures are also provided, and the settling time was within  $1.2$  ms.

Figure 21 illustrates the load voltage of  $48$  V and current waveforms at  $0.33$  kW. The sudden variation in load voltage and current took place at  $0.05$  s; the enlarged figures are also provided, and the settling time was within  $1.4$  ms.

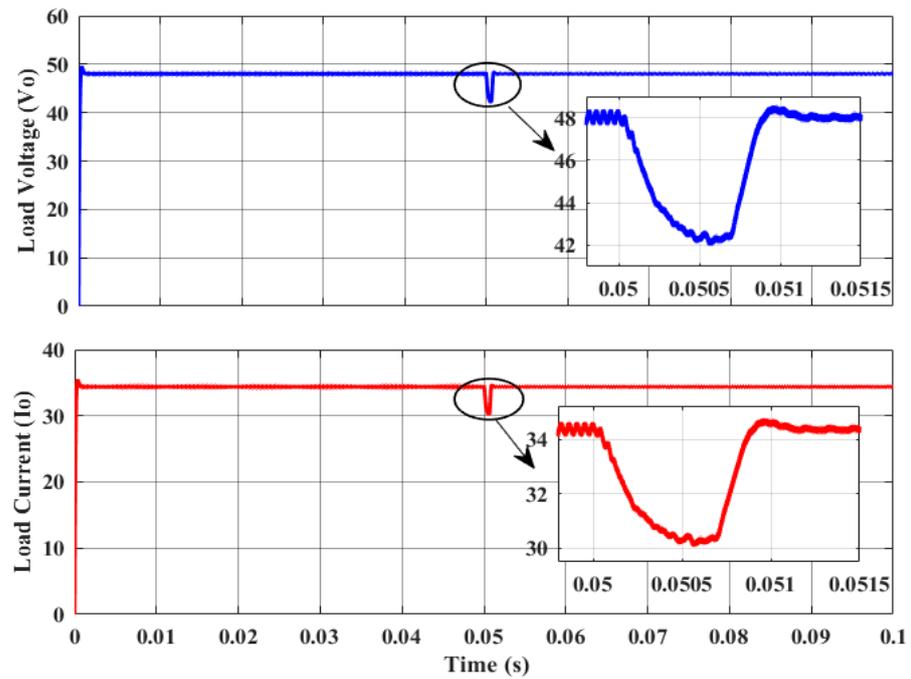


Figure 20. Step change in load voltage and current waveforms from  $500 V_{in}$  to  $300 V_{in}$  at 1.65 kW.

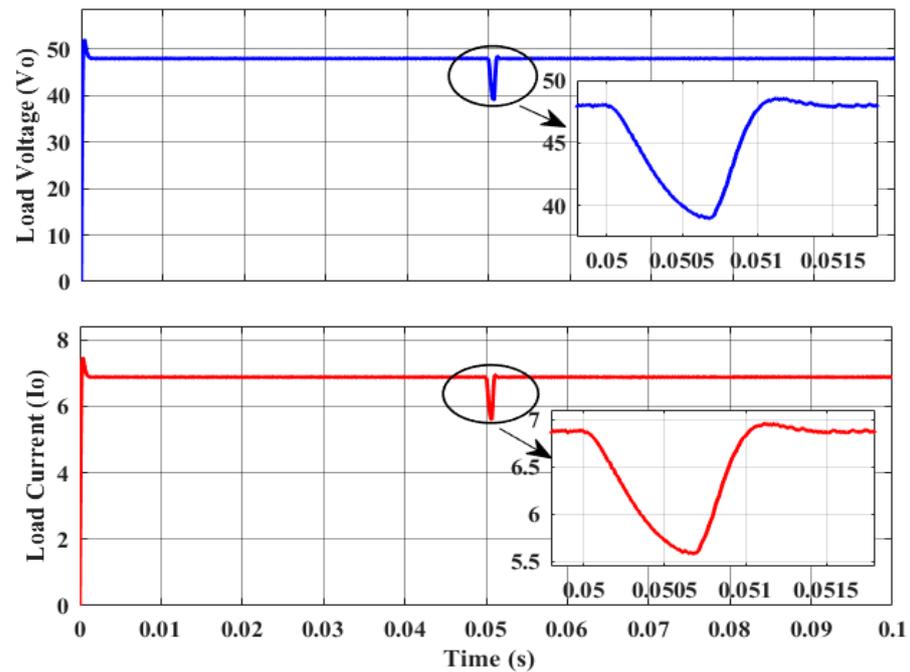


Figure 21. Step change in load voltage and current waveforms from  $500 V_{in}$  to  $300 V_{in}$  at 0.33 kW.

#### 4.3. Experimental Validation of $iL^2C$ Converter

The  $iL^2C$  converter concept is constructed utilizing GaN technology and operates at a maximum rated load capacity of 3.3 kW. The purpose of this prototype is to demonstrate the performance line and load regulation of the converter. The range of input voltages is set between  $300 V_{in}$  and  $500 V_{in}$ , while the rated load voltage is maintained at  $48 V_o$ . The converter's effectiveness is evaluated under different load conditions [39,40]. The major side of the converter includes 8-GaN switches, specifically 4 in converter 1 and 4 in converter 2.

The production specifications of the GaN switch GS66508T are listed in [24], where the critical parameters are a drain source voltage of 650 V, a drain current of 30 A, and a low drain resistance of 50 m $\Omega$ , respectively. The E-mode GaN transistor possesses advanced characteristics such as an upper cooled technology, resulting in reduced junction–case thermal resistance at high power density [41,42]. It also exhibits decreased drain resistance, reverse recovery current, and zero reverse recovery losses. Additionally, it showcases well-designed gate charge characteristics [43]. The TMS320F28335 serves as the primary controller for the iL<sup>2</sup>C converter, functioning as a digital signal processor [44,45]. The prototype was constructed according to specific modeling parameters, including a magnetizing inductance of 23  $\mu$ H for  $L_{m1}$  and  $L_{m2}$ , resonant inductors of 21  $\mu$ H for  $L_{r1}$  and  $L_{r2}$ , resonant capacitors of 56 nF for  $C_{r1}$  and  $C_{r2}$ , and a filter capacitor of 100  $\mu$ F for  $C_0$ . The experimental setup is illustrated in Figure 22.

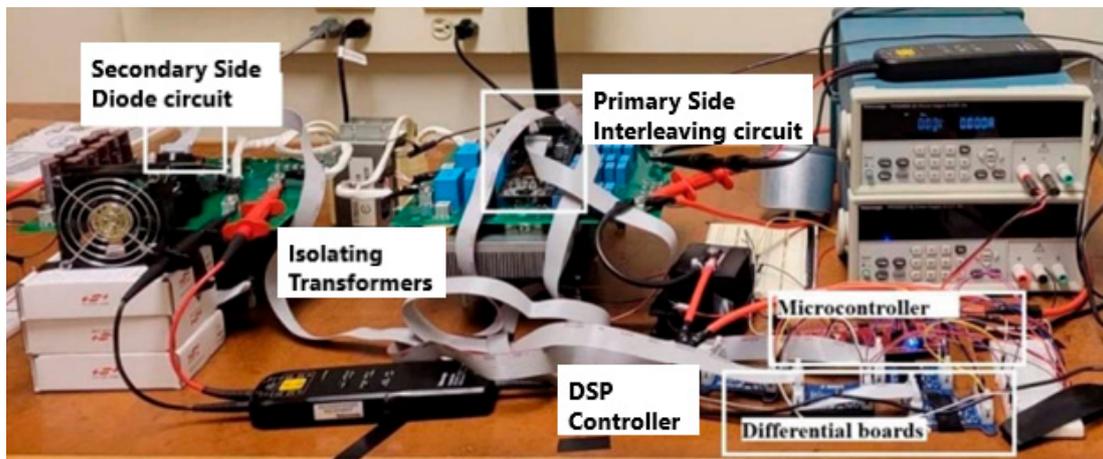


Figure 22. Experimental setup of iL<sup>2</sup>C converter for 3.3 kW [24].

Figure 23 displays the empirical waveforms of the drain and gate voltages of a switch operating with zero voltage switching (ZVS). This clearly demonstrates the successful attainment of ZVS functioning using soft switching.

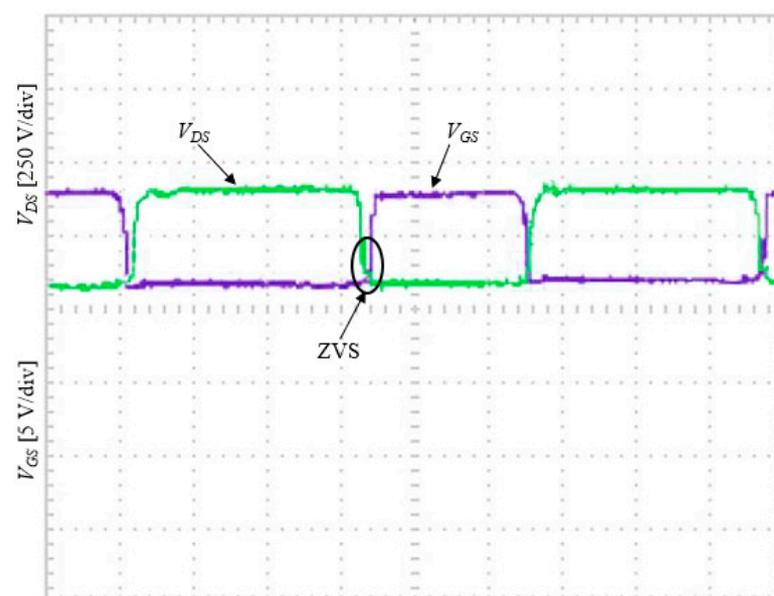
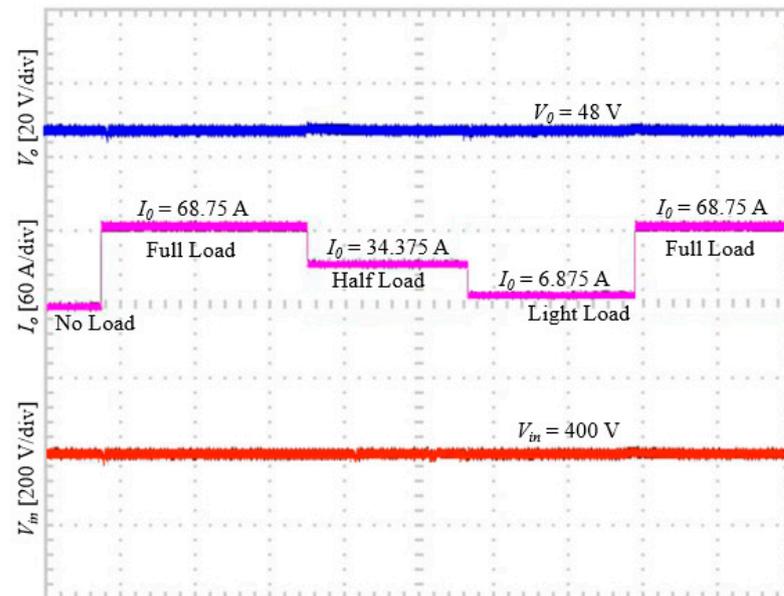


Figure 23. Validated waveforms of GaN switch  $V_{DS}$  and  $V_{GS}$ .

The load regulation of the converter was analyzed and is depicted in Figure 24 under different load situations of 3.3 kW, 1.65 kW, and 0.33 kW. The input voltage was kept constant at 400 V<sub>in</sub>, while the output voltage was maintained at 48 V<sub>o</sub>. Based on the findings, it was observed that the output voltage remained steady during load operations involving step-up and step-down conversion; this indicates effective voltage control. The findings were examined with a time scale of 100 ms for each division and a load voltage scale of 20 volts per division, shown by a blue line. The load current scale was set at 50 amperes per division, represented by a pink line. The input source voltage scale was set at 300 volts per division, represented by a red line.



**Figure 24.** Validated waveforms during load regulation.

As seen in Figure 25, the iL<sup>2</sup>C converter was validated for 3.3 kW at 48 V<sub>o</sub> and 68.75 A during variable input voltage conditions. The findings were examined with a time scale of 100 ms for each division and a load voltage scale of 20 volts per division, shown by an orange line. The load current scale was set at 50 amperes per division, represented by a pink line. The input source voltage scale was set at 300 volts per division, represented by a blue line. The dynamic responses at the line side were executed by introducing an abrupt alteration in input voltage at 0.05 s (500 ms), resulting in a little modification in load voltage. The corresponding current was then monitored and recorded, as depicted in Figure 25. The converter and controller demonstrated conformity with the theoretical and simulated studies.

The efficiency of the GaN-powered iL<sup>2</sup>C converter was evaluated at the recommended voltage settings of 400 V<sub>in</sub> and 48 V<sub>o</sub>. The efficiency was measured at various load conditions, specifically 3.3 kW, 3.0 kW, 2.5 kW, 2.0 kW, 1.65 kW, 1.0 kW, 0.5 kW, and 0.33 kW, sequentially. The efficiency was 98.2% at a power output of 3.3 kW, 98.7% at a power output of 1.65 kW, and 99.1% at a power output of 0.33 kW. Figure 26 displays the efficiency curve in relation to power.

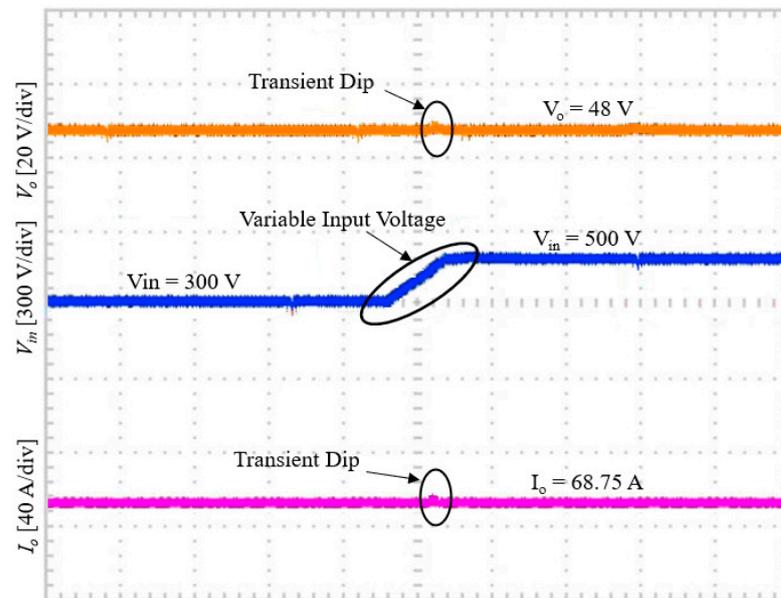


Figure 25. Validated waveforms during regulated line voltage.

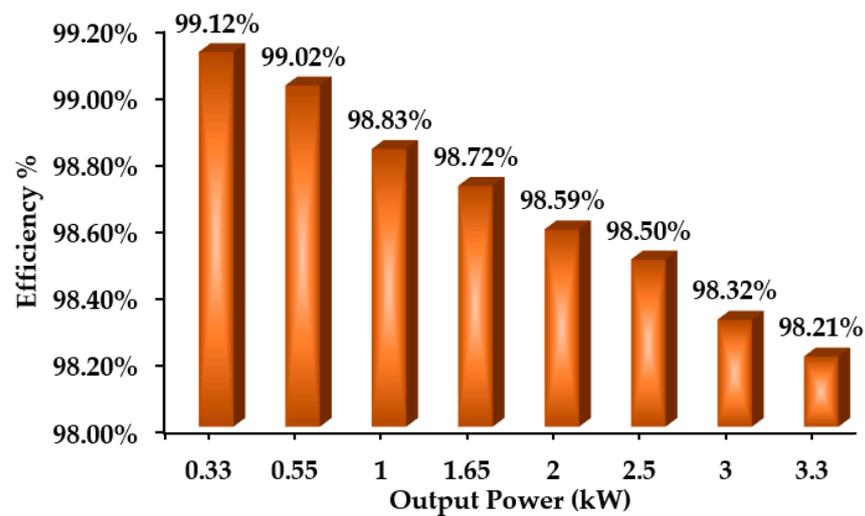


Figure 26. Efficiency vs. power.

## 5. Performance Analysis and Discussion

This section examines the steady-state and dynamic performance assessment of the converter in relation to line regulation and load regulation. The comparative assessment of simulation and experimental analysis of the converter was carried out during various conditions presented in Section 4. Moreover, the converter's merits are discussed under various parameters at the end of this section.

### 5.1. Steady-State Performance Analysis

This analysis was conducted at constant input and load voltages, while varying the load. The voltage deviation and ripple percentage were measured to be +0.5 V (+1.04%), +0.3 V (+0.62%), and +0.15 V (+0.31%) at power levels of 3.3 kW, 1.65 kW, and 0.33 kW, respectively. Figures 27 and 28 show the steady-state analysis under simulating conditions of load voltage deviation (LVD), average voltage ripple (%AVR), load current deviation (LCD), and average current ripple (%ACR), respectively [24]. The present discrepancy and fluctuation percentages were measured to be +0.65 A (+0.94%), +0.175 A (+0.5%), and +0.017 A (+0.25%) at power levels of 3.3 kW, 1.65 kW, and 0.33 kW, correspondingly.

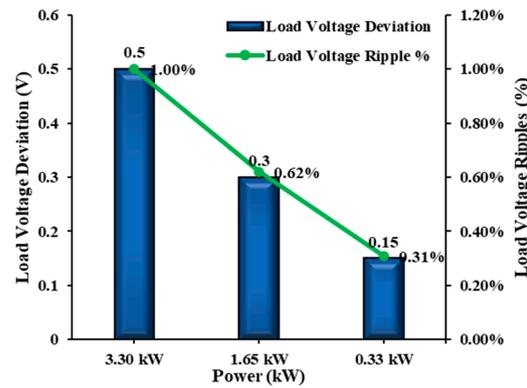


Figure 27. Steady-state analysis of LVD vs. %AVR during simulations.

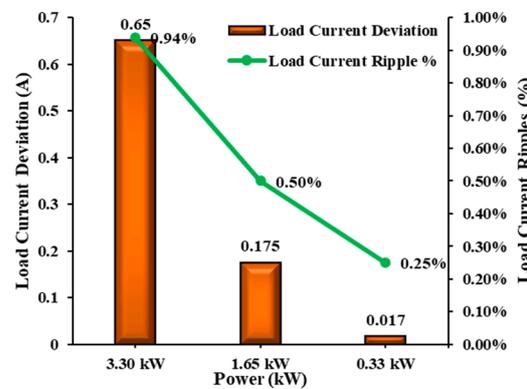


Figure 28. Steady-state analysis of LCD vs. %ACR during simulations.

The voltage variation and ripple percentage were measured to be +0.9 V (+1.87%), +0.7 V (+1.45%), and +0.52 V (+1.09%) for power levels of 3.3 kW, 1.65 kW, and 0.33 kW, respectively. Figures 29 and 30 show the steady-state analysis under experimental conditions of LVD, %AVR, LCD, and %ACR, respectively [24]. The present difference and fluctuation percentages were measured as +1.26 A (+1.83%), +0.525 A (+1.52%), and +0.095 A (+1.23%) at power levels of 3.3 kW, 1.65 kW, and 0.33 kW, respectively.

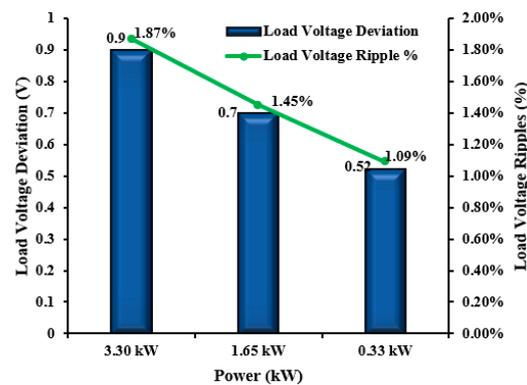


Figure 29. Steady-state analysis of LVD vs. %AVR during experimental validation.

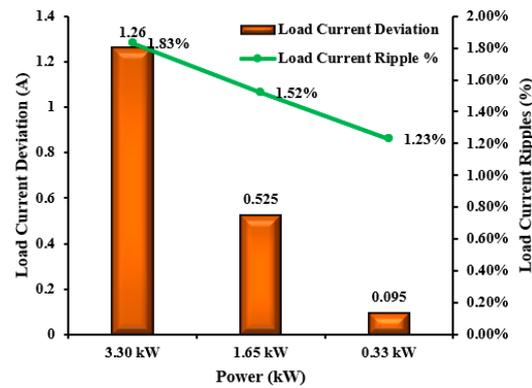


Figure 30. Steady-state analysis of LCD vs. %ACR during experimental validation.

### 5.2. Transient Performance Analysis

Table 1 shows the transient analysis during simulation conditions of the load voltage deviations, %avg load ripples, transient dip, and %avg dip of the voltage during line regulation (i.e., 300  $V_{in}$ –500  $V_{in}$  and 500  $V_{in}$ –300  $V_{in}$ ) tabulated by maintaining the load voltage at 48  $V_0$  and the load current at 68.75 A, 38.375 A, and 6.875 A, respectively. When the load was 3.3 kW, for (300  $V_{in}$ –500  $V_{in}$ ) and (500  $V_{in}$ –300  $V_{in}$ ), the max LVD was found to be +0.40 V and +0.42 V, and the %ALVR was +0.830% and +0.875%, respectively. The transient voltage dip was found to be +5.2 V, –3.5 V, and its average percentage dip was +10.83%, –7.29%, respectively, with a settling time of 1.1 ms and 1.2 ms. In the case of 1.65 kW, the max LVD was found to be +0.38 V and +0.40 V, and the %ALVR was +0.791% and +0.833%, respectively. The transient voltage dip was found to be +4.8 V, –5.8 V, and its average percentage dip was +10.00%, –12.08%, respectively, with a settling time of 1.0 ms and 1.2 ms. Lastly, in the case of 0.33 kW, the max LVD was found to be +0.37 V and +0.38 V, and the %ALVR was +0.770% and +0.791%, respectively. The transient voltage dip was found to be +6.35 V, –8.70 V, and its average percentage dip was +13.23%, –18.12%, respectively, with a settling time of 1.33 ms and 1.4 ms.

Table 1. Transient analysis under line regulation during simulations.

Operation Attributes	Variable Input Voltage	Max. LVD	% ALVR	Transient Analysis			
				Voltage Dip	Avg % of Dip	Settling Time	
Load Variation	3.3 kW	300 V–500 V	+0.40 V	+0.830%	+5.2 V	+10.83%	1.1 ms
		500 V–300 V	+0.42 V	+0.875%	–3.5 V	–7.29%	1.2 ms
	1.65 kW	300 V–500 V	+0.38 V	+0.791%	+4.8 V	+10.00%	1.0 ms
		500 V–300 V	+0.40 V	+0.833%	–5.8 V	–12.08%	1.2 ms
	0.33 kW	300 V–500 V	+0.37 V	+0.770%	+6.35 V	+13.23%	1.33 ms
		500 V–300 V	+0.38 V	+0.791%	–8.70 V	–18.12%	1.40 ms

Table 2 shows the transient analysis during simulation conditions of the load current deviations, %avg load ripples, transient dip, and %avg dip of the current during line regulation (i.e., 300  $V_{in}$ –500  $V_{in}$  and 500  $V_{in}$ –300  $V_{in}$ ) tabulated by maintaining the load voltage at 48  $V_0$  and the load current at 68.75 A, 38.375 A, and 6.875 A, respectively. When the load was 3.3 kW, for (300  $V_{in}$ –500  $V_{in}$ ) and (500  $V_{in}$ –300  $V_{in}$ ), the max LCD was found to be +0.59 A and +0.64 A, and the %ALCR was +0.85% and +0.93%, respectively. The transient current dip was found to be +7.25 A, –4.75 A, and its average percentage dip was +10.54%, –6.90%, respectively, with a settling time of 1.1 ms and 1.2 ms. In the case of 1.65 kW, the max LCD was found to be +0.57 A and +0.62 A, and the %ALCR was +1.66% and +1.81%, respectively. The transient current dip was found to be +3.82 A, –2.25 A, and

its average percentage dip was +11.11%, −6.54%, respectively, with a settling time of 1.0 ms and 1.2 ms. Lastly, in the case of 0.33 kW, the max LCD was found to be +0.055 A and +0.069 A, and the %ALCR was +0.8% and +1.0%, respectively. The transient current dip was found to be +1.85 A, −1.87 A, and its average percentage dip was +26.91%, −27.20%, respectively, with a settling time of 1.33 ms and 1.40 ms.

**Table 2.** Transient analysis of load current under line regulation during simulation.

Operation Attributes	Variable Input Voltage	Max. LCD	%ALCR	Transient Analysis			
				Current Dip	Avg % of Dip	Settling Time	
Load Variation	3.3 kW	300 V–500 V	+0.59 A	+0.85%	+7.25 A	+10.54%	1.1 ms
		500 V–300 V	+0.64 A	+0.93%	−4.75 A	−6.90%	1.2 ms
	1.65 kW	300 V–500 V	+0.57 A	+1.66%	+3.82 A	+11.11%	1.0 ms
		500 V–300 V	+0.62 A	+1.81%	−2.25 A	−6.54%	1.2 ms
	0.33 kW	300 V–500 V	+0.055 A	+0.8%	+1.85 A	+26.91%	1.33 ms
		500 V–300 V	+0.069 A	+1.0%	−1.87 A	−27.20%	1.40 ms

In addition, line regulations were conducted experimentally under variable input with a full load condition at 3.3 kW. Table 3 presents the comparative analysis of simulation and experimental conditions [24]. The simulation and experimental results indicate that the steady-state voltage deviation was +0.4 V (+0.83%) and +0.76 V (+1.58%), while the steady-state current deviation was +0.59 A (+0.85%) and +1.38 A (+2.0%), correspondingly.

**Table 3.** Simulation vs. experimental analysis during line regulation.

Conditions	Max. LVD	%AVR	Max. LCD	%ACR
Simulations	+0.40 V	+0.83%	+0.59 A	+0.85%
Experimental	+0.76 V	+1.58%	+1.38 A	+2.00%

The measurements in Table 4 indicate that there was a transient voltage dip (TVD) of +5.2 V (+10.83%), +6.17 V (+12.85%) and a transient current dip (TCD) of +7.25 A (+10.54%), +8.29 A (+12.05%), which are the transient voltage ripple (TVR) percentage and transient current ripple (TCR) percentage, respectively. The computational and experimental results indicate that the transient dip had a duration of 1.1 ms and 18 ms, respectively.

**Table 4.** Simulation vs. experimental transient analysis during line regulation.

Conditions	Voltage Dip	Avg% of Dip	Current Dip	Avg% of Dip	Settling Time
Simulations	+5.20 V	+10.83%	+7.25 A	+10.54%	1.1 ms
Experimental	+6.17 V	+12.85%	+8.29 A	+12.05%	18 ms

### 5.3. Discussion

The presented technology has the merit of scalability in operation, where it can operate in a wide range; ease of adaptability to any type of charging environment; and a high efficiency of operation. The major constraint of this technology is basically the construction of a complex system, and the management of the control algorithms for two bridges with maintaining the proper deadtime is the major challenge. The complexity of managing the two resonant tanks with hybrid structures will lead to a high cost of the system. The assembly, manufacturing, and fabrication of the proposed system having the higher involvement of complex strategies to minimize the losses during the development phase; this happens due to the system's complexity.

## 6. Conclusions

This study focused on analyzing the  $iL^2C$  resonant DC-DC converter, which utilizes a hybrid control method known as the variable frequency + phase shift modulation (VFPSM) technique. This research also contributes to the advancement of EV charging technology, ensuring efficient and reliable charging for xEVs. The converter is designed to accommodate a wide range of input voltages and is specifically intended for use in EV charging systems. This paper provides an explanation of the modeling and operational principles of the converter, and it conducts simulations of the whole proposed design using MATLAB/Simulink. The performance of the  $iL^2C$  converter is evaluated under several conditions, and initially the converter is tested at various load and line conditions. Furthermore, the performance of the converter is verified through experimental validation utilizing GaN switches, and the results indicate that the controller effectively regulates the system. In future expansion of this work, predicative control techniques are to be implemented and analyzed.

**Author Contributions:** Conceptualization, R.P.N. and A.D.; Methodology, R.P.N. and A.S.T.; Validation, R.P.N.; Formal analysis, R.P.N. and S.M.; Investigation, R.P.N. and A.D.; Resources, R.P.N.; Writing—original draft, R.P.N. and A.S.T.; Writing—review & editing, R.P.N., S.M. and A.D.; Visualization, R.P.N.; Supervision, S.M., A.D. and A.S.T. All authors have read and agreed to the published version of the manuscript.

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## Abbreviations

The abbreviations used in this paper are summarized as follows:

BEV	Battery Electric Vehicle
ACR	Average Current Ripple
AVR	Average Voltage Ripple
E-mode	Enhancement Mode
EV	Electric Vehicle
FCEV	Fuel Cell Electric Vehicle
GaN	Gallium Nitride
HEV	Hybrid Electric Vehicle
ICE	Internal Combustion Engine
$iL^2C$	Interleaved Inductor–Inductor–Capacitor
$L^2C$	Inductor–Inductor–Capacitor
LCD	Load Current Deviation
LVD	Load Voltage Deviation
PHEV	Plugin Hybrid Electric Vehicle
SCEV	Super Capacitor Electric Vehicle
TCD	Transient Current Dip
TCR	Transient Current Ripple
TVD	Transient Voltage Dip
TVR	Transient Voltage Ripple
UCEV	Ultra-Capacitor Electric Vehicle
VCO	Voltage Control Oscillator
VFPSM	Variable Frequency Phase Shift Modulation
ZCS	Zero Current Switching
ZVS	Zero Voltage Switching

## References

1. Mopidevi, S.; Narasipuram, R.P.; Aemalla, S.R.; Rajan, H. Emobility: Impacts and analysis of future transportation electrification market in economic, renewable energy and infrastructure perspective. *Int. J. Powertrains* **2022**, *11*, 264–284. [\[CrossRef\]](#)
2. Zhou, K.; Wu, Y.; Wu, X.; Sun, Y.; Teng, D.; Liu, Y. Research and Development Review of Power Converter Topologies and Control Technology for Electric Vehicle Fast-Charging Systems. *Electronics* **2023**, *12*, 1581. [\[CrossRef\]](#)
3. Shahjalal, M.; Shams, T.; Tasnim, M.N.; Ahmed, R.; Ahsan, M.; Haider, J. A Critical Review on Charging Technologies of Electric Vehicles. *Energies* **2022**, *15*, 8239. [\[CrossRef\]](#)
4. Ilahi, T.; Izhar, T.; Zahid, M.; Rasool, A.; Tsamaase, K.; Zahid, T.; Khan, E.M. Design Analysis of High-Power Level 4 Smart Charging Infrastructure Using Next-Generation Power Devices for EVs and Heavy Duty EVs. *World Electr. Veh. J.* **2024**, *15*, 66. [\[CrossRef\]](#)
5. Narasipuram, R.P.; Mopidevi, S. A technological overview & design considerations for developing electric vehicle charging stations. *J. Energy Storage* **2021**, *43*, 103225. [\[CrossRef\]](#)
6. Deng, J.; Li, S.; Hu, S.; Mi, C.C.; Ma, R. Design Methodology of LLC Resonant Converters for Electric Vehicle Battery Chargers. *IEEE Trans. Veh. Technol.* **2014**, *63*, 1581–1592. [\[CrossRef\]](#)
7. Domajanko, J.; Prosen, N. A Wireless Power Transfer System Using a Double DD Quadrature Coil Structure. *Electronics* **2023**, *12*, 890. [\[CrossRef\]](#)
8. Far, M.F.; Miljavec, D.; Manko, R.; Pippuri-Mäkeläinen, J.; Ranta, M.; Keränen, J.; Kinder, J.; Vukotić, M. Modular and Scalable Powertrain for Multipurpose Light Electric Vehicles. *World Electr. Veh. J.* **2023**, *14*, 309. [\[CrossRef\]](#)
9. Cervero, D.; Fotopoulou, M.; Muñoz-Cruzado, J.; Rakopoulos, D.; Stergiopoulos, F.; Nikolopoulos, N.; Voutetakis, S.; Sanz, J.F. Solid State Transformers: A Critical Review of Projects with Relevant Prototypes and Demonstrators. *Electronics* **2023**, *12*, 931. [\[CrossRef\]](#)
10. Beiranvand, R.; Rashidian, B.; Zolghadri, M.R.; Alavi, S.M.H. A Design Procedure for Optimizing the LLC Resonant Converter as a Wide Output Range Voltage Source. *IEEE Trans. Power Electron.* **2012**, *27*, 3749–3763. [\[CrossRef\]](#)
11. Musavi, F.; Craciun, M.; Gautam, D.S.; Eberle, W.; Dunford, W.G. An LLC resonant DC–DC converter for wide output voltage range battery charging applications. *IEEE Trans. Power Electron.* **2013**, *28*, 5437–5445. [\[CrossRef\]](#)
12. Kim, B.-C.; Park, K.-B.; Kim, C.-E.; Moon, G.-W. Load sharing characteristic of two-phase interleaved LLC resonant converter with parallel and series input structure. In Proceedings of the 2009 IEEE Energy Conversion Congress and Exposition (ECCE), San Jose, CA, USA, 20–24 September 2009; pp. 750–753.
13. Guo, B.; Zhang, Y.; Zhang, J.; Gao, J. Hybrid Control Strategy of Phase-Shifted Full-Bridge LLC Converter Based on Digital Direct Phase-Shift Control. *J. Power Electron.* **2018**, *18*, 802–816.
14. Zhou, B.; Zhao, C.; Luo, H.; Qiu, Y.; Chen, S.; Zang, T.; Zhou, Y.; Zhou, X.; Zhao, H. Hybrid Control Strategy for Single-Stage Interleaved Totem-Pole LLC AC-DC Converter With Input and Output Power Decoupling. *IEEE Trans. Power Electron.* **2024**, *39*, 5135–5154. [\[CrossRef\]](#)
15. Yoo, K.-M.; Lee, J.-Y. A 10-kW Two-Stage Isolated/Bidirectional DC/DC Converter with Hybrid-Switching Technique. *IEEE Trans. Ind. Electron.* **2013**, *60*, 2205–2213. [\[CrossRef\]](#)
16. Mortazavizadeh, S.A.; Palazzo, S.; Amendola, A.; De Santis, E.; Di Ruzza, D.; Panariello, G.; Sanseverino, A.; Velardi, F.; Busatto, G. High Frequency, High Efficiency, and High Power Density GaN-Based LLC Resonant Converter: State-of-the-Art and Perspectives. *Appl. Sci.* **2021**, *11*, 11350. [\[CrossRef\]](#)
17. Shadnam Zarbil, M.; Khalifeh, M.; Vahedi, A. A real-time LabVIEW-based emulator for various types of electrical loads. *Electr. Eng.* **2022**, *104*, 4367–4378. [\[CrossRef\]](#)
18. Maurya, R.; Arya, S.R.; Saini, R.K.; Gupta, J. On-board power quality charger for electric vehicles with minimized switching stresses. *Electr. Eng.* **2022**, *104*, 1667–1680. [\[CrossRef\]](#)
19. Bayati, M.; Abedi, M.; Gharehpetian, G.B.; Farahmandrad, M. Two designs for DC–DC stage of electric vehicle charging stations. *Electr. Eng.* **2020**, *102*, 2389–2399. [\[CrossRef\]](#)
20. Wang, H.; Dusmez, S.; Khaligh, A. Design and analysis of a full-bridge LLC-based PEV charger optimized for wide battery voltage range. *IEEE Trans. Veh. Technol.* **2014**, *63*, 1603–1613. [\[CrossRef\]](#)
21. Narasipuram, R.P.; Mopidevi, S. A Novel Hybrid Control Strategy and Dynamic Performance Enhancement of a 3.3 kW GaN–HEMT-Based iL2C Resonant Full-Bridge DC–DC Power Converter Methodology for Electric Vehicle Charging Systems. *Energies* **2023**, *16*, 5811. [\[CrossRef\]](#)
22. Narasipuram, R.P.; Mopidevi, S. Parametric Modelling of Interleaved Resonant DC–DC Converter with Common Secondary Rectifier Circuit for xEV Charging Applications. In Proceedings of the 2023 International Conference on Sustainable Emerging Innovations in Engineering and Technology (ICSEIET), Ghaziabad, India, 14–15 September 2023; pp. 842–846.
23. Narasipuram, R.P.; Mopidevi, S. A Dual Primary Side FB DC-DC Converter with Variable Frequency Phase Shift Control Strategy for On/Off Board EV Charging Applications. In Proceedings of the 2023 9th IEEE India International Conference on Power Electronics (IICPE), Sonapat, India, 28–30 November 2023; pp. 1–5.
24. Narasipuram, R.P.; Mopidevi, S. An industrial design of 400 V-48 V, 98.2% peak efficient charger using E-mode GaN technology with wide operating ranges for xEV applications. *Int. J. Numer. Model. Electron. Netw. Devices Fields* **2024**, *37*, e3194. [\[CrossRef\]](#)
25. Xi, J.; Si, H.; Gao, J. Optimization of a Shift Control Strategy for Pure Electric Commercial Vehicles Based on Driving Intention. *World Electr. Veh. J.* **2024**, *15*, 44. [\[CrossRef\]](#)

26. Althurthi, S.B.; Rajashekara, K.; Debnath, T. Comparison of EV Fast Charging Protocols and Impact of Sinusoidal Half-Wave Fast Charging Methods on Lithium-Ion Cells. *World Electr. Veh. J.* **2024**, *15*, 54. [[CrossRef](#)]
27. Zulauf, G.; Park, S.; Liang, W.; Surakitbovorn, K.N.; Rivas-Davila, J. COSS Losses in 600 V GaN Power Semiconductors in Soft-Switched, High- and Very-High-Frequency Power Converters. *IEEE Trans. Power Electron.* **2018**, *33*, 10748–10763. [[CrossRef](#)]
28. Van Do, T.; Trovao, J.P.F.; Li, K.; Boulon, L. Wide-Bandgap Power Semiconductors for Electric Vehicle Systems: Challenges and Trends. *IEEE Veh. Technol. Mag.* **2021**, *16*, 89–98. [[CrossRef](#)]
29. Gu, W.-J.; Harada, K. A new method to regulate resonant converters. *IEEE Trans. Power Electron.* **1988**, *3*, 430–439. [[CrossRef](#)]
30. Bosshard, T.R.; Kolar, J.W. Performance comparison of a GaN GIT and a Si IGBT for high-speed drive applications. In Proceedings of the 2014 International Power Electronics Conference (IPEC-Hiroshima 2014—ECCE ASIA), Hiroshima, Japan, 18–21 May 2014.
31. Narasipuram, R.P.; Karkhanis, V.A.; Ellinger, M.; Saranath, K.M.; Alagarsamy, G.; Jadhav, R. *Systems Engineering—A Key Approach to Transportation Electrification. Symposium on International Automotive Technology*; SAE Technical Paper, 2024-26-0128; SAE International: Warrendale, PA, USA, 2024.
32. Elrajoubi, A.M.; Ang, S.S.; George, K. Design and analysis of a new GaN-Based AC/DC converter for battery charging application. *IEEE Trans. Ind. Appl.* **2019**, *55*, 4044–4052. [[CrossRef](#)]
33. Pushpakaran, B.N.; Subburaj, A.S.; Bayne, S.B. Commercial GaN-Based Power Electronic Systems: A Review. *J. Electron. Mater.* **2020**, *49*, 6247–6262. [[CrossRef](#)]
34. Keshmiri, N.; Wang, D.; Agrawal, B.; Hou, R.; Emadi, A. Current Status and Future Trends of GaN HEMTs in Electrified Transportation. *IEEE Access* **2020**, *8*, 70553–70571. [[CrossRef](#)]
35. Chellappan, S. *Design Considerations of GaN Devices for Improving Power Converter Efficiency*; Texas Instruments Inc.: Dallas, TX, USA, 2017.
36. Yadlapalli, R.T.; Kotapati, A.; Kandipati, R.; Balusu, S.R.; Koritala, C.S. Advancements in energy efficient GaN power devices and power modules for electric vehicle applications: A review. *Int. J. Energy Res.* **2021**, *45*, 12638–12664. [[CrossRef](#)]
37. Lidow, A.; Strydom, J.; Strittmatter, R.; Zhou, C. GaN: A Reliable Future in Power Conversion: Dramatic performance improvements at a lower cost. *IEEE Power Electron. Mag.* **2015**, *2*, 20–26. [[CrossRef](#)]
38. Will, C.; Ocker, F. Flexibility Potential of Smart Charging Electric Trucks and Buses. *World Electr. Veh. J.* **2024**, *15*, 56. [[CrossRef](#)]
39. Lei, H.; Hu, X.; Zhao, J.; Deng, D.; Wang, R. Research Progress and Prospects of Public Transportation Charging Station Layout Methods. *World Electr. Veh. J.* **2024**, *15*, 63. [[CrossRef](#)]
40. Zheng, J.; Du, Y.; Chen, D.; Ying, W.; Zhao, H.; Liu, K.; Qiu, J. Resonant Gate Drive Circuit with Active Clamping to Increase Efficiency and Reliability. *World Electr. Veh. J.* **2024**, *15*, 74. [[CrossRef](#)]
41. Bernard, K. *Advantages of Using Gallium Nitride FETs in Satellite Applications*; Renesas: Tokyo, Japan, 2018.
42. Wang, Y.; Ding, Y.; Yin, Y. Reliability of Wide Band Gap Power Electronic Semiconductor and Packaging: A Review. *Energies* **2022**, *15*, 6670. [[CrossRef](#)]
43. Al Attar, H.; Hamida, M.A.; Ghanes, M.; Taleb, M. LLC DC-DC Converter Performances Improvement for Bidirectional Electric Vehicle Charger Application. *World Electr. Veh. J.* **2022**, *13*, 2. [[CrossRef](#)]
44. Bottaro, E.; Rizzo, S.A.; Salerno, N. Circuit Models of Power MOSFETs Leading the Way of GaN HEMT Modelling—A Review. *Energies* **2022**, *15*, 3415. [[CrossRef](#)]
45. Wei, Y.; Luo, Q.; Wang, Z.; Mantooth, H.A. A Complete Step-by-Step Optimal Design for LLC Resonant Converter. *IEEE Trans. Power Electron.* **2021**, *36*, 3674–3691. [[CrossRef](#)]

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